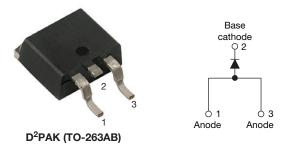
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High Voltage Surface Mount Input Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	10 A						
V _R	1200 V						
V _F at I _F	1.1 V						
I _{FSM}	160 A						
T _J max.	150 °C						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- · Glass passivated pellet chip junction
- AEC-Q101 gualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Input rectification
- · On-board and off-board EV / HEV battery chargers

DESCRIPTION

The VS-10ETS12SLHM3 rectifier series has been optimized for very low forward voltage drop, with moderate leakage.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	12.0	16.0	А						

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Sinusoidal waveform	10	А						
V _{RRM}		1200	V						
I _{FSM}		160	A						
V _F	10 A, T _J = 25 °C	1.1	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-10ETS12SLHM3	1200	1300	0.5



HALOGEN

FREE

VS-10ETS12SLHM3



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ABSOLUTE MAXIMUM RATING	S			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180° conduction half sine wave	10	
Maximum peak one cycle		10 ms sine pulse, rated V_{RRM} applied	135	А
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	160	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	91	A ² s
Maximum r-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	130	A-2
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1290	A²√s

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST (VALUES	UNITS				
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C	1.1	V				
Forward slope resistance	r _t	T.I = 150 °C	20	mΩ				
Threshold voltage	V _{F(TO)}	IJ = 150 C		0.82	V			
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V_{-} roted V_{-}	0.05	mA			
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = rated V _{RRM}	0.50	ШA			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W				
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	0/10				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Marking device		Case style D ² PAK (TO-263AB)	10ETS	12SH				

Note

 $^{(1)}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W.



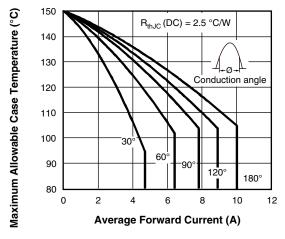


Fig. 1 - Current Rating Characteristics

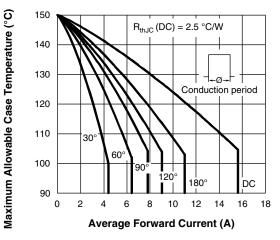


Fig. 2 - Current Rating Characteristics

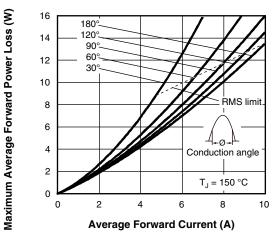
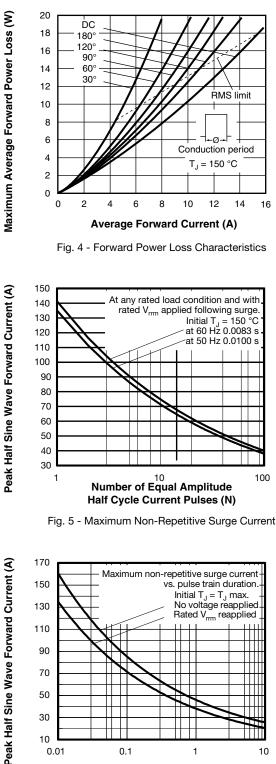


Fig. 3 - Forward Power Loss Characteristics

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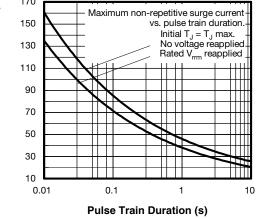


Fig. 6 - Maximum Non-Repetitive Surge Current

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VS-10ETS12SLHM3

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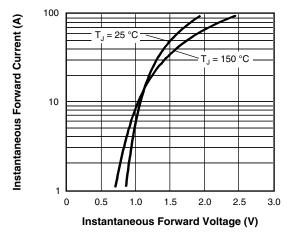


Fig. 7 - Forward Voltage Drop Characteristics

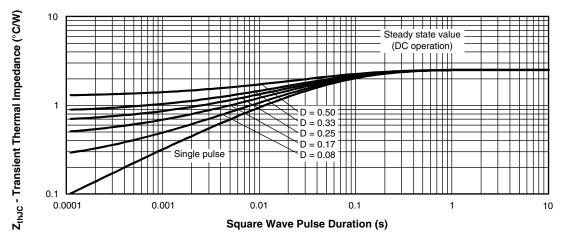


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



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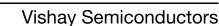
ORDERING INFORMATION TABLE

Device code	VS-	10	Е	т	S	12	S	L	н	М3
	1	2	3	4	5	6	7	8	9	10
	1	- Visl	hay Sen	nicondul	tors proc	duct				
	2 -	Cur	rent rati	ng (10 =	= 10 A)					
	3 -	Circ	uit conf	iguratior	ו:					
		E	E = single							
	4 -	Pac	Package:							
		Т	= D ² PA	K (TO-2	63AB)					
	5 -		e of silio	-	,					
				ard reco	overy ree	ctifier				
	6 -			le x 100	-			12 = 12	00 V	
	7 -			mounta		•	L			
	8 .					ted) fo	r diffore	nt orien	tation	
			L = tape and reel (left oriented), for different orientation, contact factory							
	9			- 101 qua	alified					
	10			ntal digit						
				-						
		M3	= halog	en-free,	RoHS-	complia	int, and	termina	ations le	ad (Pb)-

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-10ETS12SLHM3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96317					

Outline Dimensions

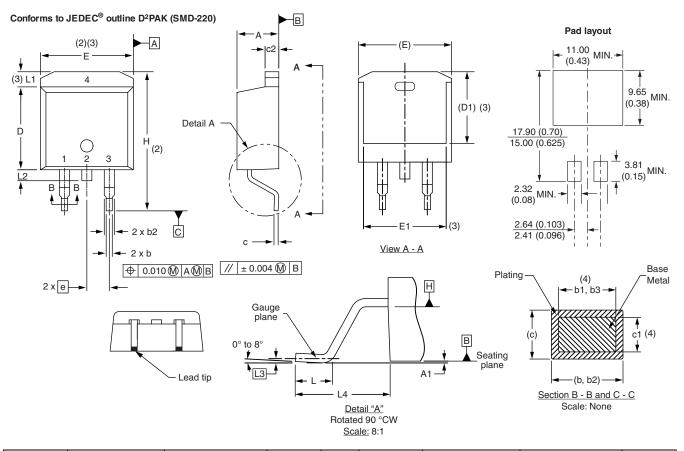


D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES		MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

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